

# HD74HC442, HD74HC443, HD74HC444

Quad. Tridirectional Bus Transceiver  
(with noninverted 3-state outputs)

Quad. Tridirectional Bus Transceiver  
(with inverted 3-state outputs)

Quad Tridirectional Bus Transceiver  
(with noninverted/inverted 3-state outputs)

REJ03D0627-0200  
(Previous ADE-205-506)  
Rev.2.00  
Mar 30, 2006

## Description

These bus transceivers are designed for a synchronous three-way communication between four-line data buses. They give the designer a choice of selecting inverting, noninverting or a combination of inverting and noninverting data paths with 3-state outputs.

The  $S_0$  and  $S_1$  inputs select the bus from which data are to be transferred. The  $\bar{G}$  inputs enable the bus or buses to which data are to be transferred. The port for any bus selected for input and any other bus not enabled for output will be at high impedance.

## Features

- High Speed Operation
- High Output Current: Fanout of 15 LSTTL Loads
- Wide Operating Voltage:  $V_{CC} = 2$  to 6 V
- Low Input Current: 1  $\mu$ A max
- Low Quiescent Supply Current:  $I_{CC}$  (static) = 4  $\mu$ A max ( $T_a = 25^\circ\text{C}$ )
- Ordering Information

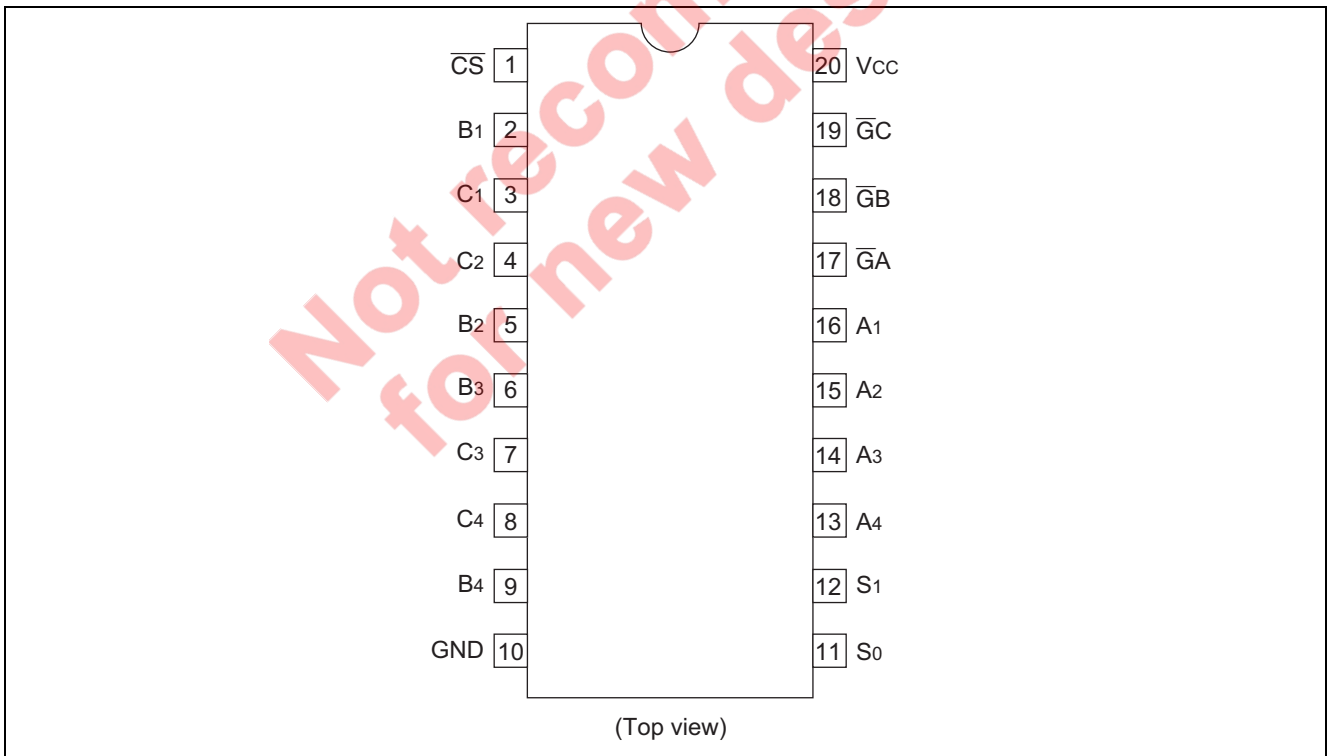
Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74HC442RPEL HD74HC443RPEL HD74HC444RPEL	SOP-20 pin (JEDEC)	PRSP0020DC-A (FP-20DBV)	RP	EL (1,000 pcs/reel)

**Function Table**

Inputs						Transfers Between Buses		
$\overline{CS}$	$S_1$	$S_0$	$\overline{GA}$	$\overline{GB}$	$\overline{GC}$	HD74HC442	HD74HC443	HD74HC444
H	X	X	X	X	X	None	None	None
X	H	H	X	X	X	None	None	None
X	X	X	H	H	H	None	None	None
X	L	L	X	H	H	None	None	None
X	L	H	H	X	H	None	None	None
X	H	L	H	H	X	None	None	None
L	L	L	X	L	L	$A \rightarrow B, A \rightarrow C$	$\overline{A} \rightarrow B, \overline{A} \rightarrow C$	$\overline{A} \rightarrow B, \overline{A} \rightarrow C$
L	L	H	L	X	L	$B \rightarrow C, B \rightarrow A$	$\overline{B} \rightarrow C, \overline{B} \rightarrow A$	$B \rightarrow C, \overline{B} \rightarrow A$
L	H	L	L	L	X	$C \rightarrow A, C \rightarrow B$	$\overline{C} \rightarrow A, \overline{C} \rightarrow B$	$\overline{C} \rightarrow A, C \rightarrow B$
L	L	L	X	L	H	$A \rightarrow B$	$\overline{A} \rightarrow B$	$\overline{A} \rightarrow B$
L	L	H	H	X	L	$B \rightarrow C$	$\overline{B} \rightarrow C$	$B \rightarrow C$
L	H	L	L	H	X	$C \rightarrow A$	$\overline{C} \rightarrow A$	$\overline{C} \rightarrow A$
L	L	L	X	H	L	$A \rightarrow C$	$\overline{A} \rightarrow C$	$\overline{A} \rightarrow C$
L	L	H	L	X	H	$B \rightarrow A$	$\overline{B} \rightarrow A$	$\overline{B} \rightarrow A$
L	H	L	H	L	X	$C \rightarrow B$	$\overline{C} \rightarrow B$	$C \rightarrow B$

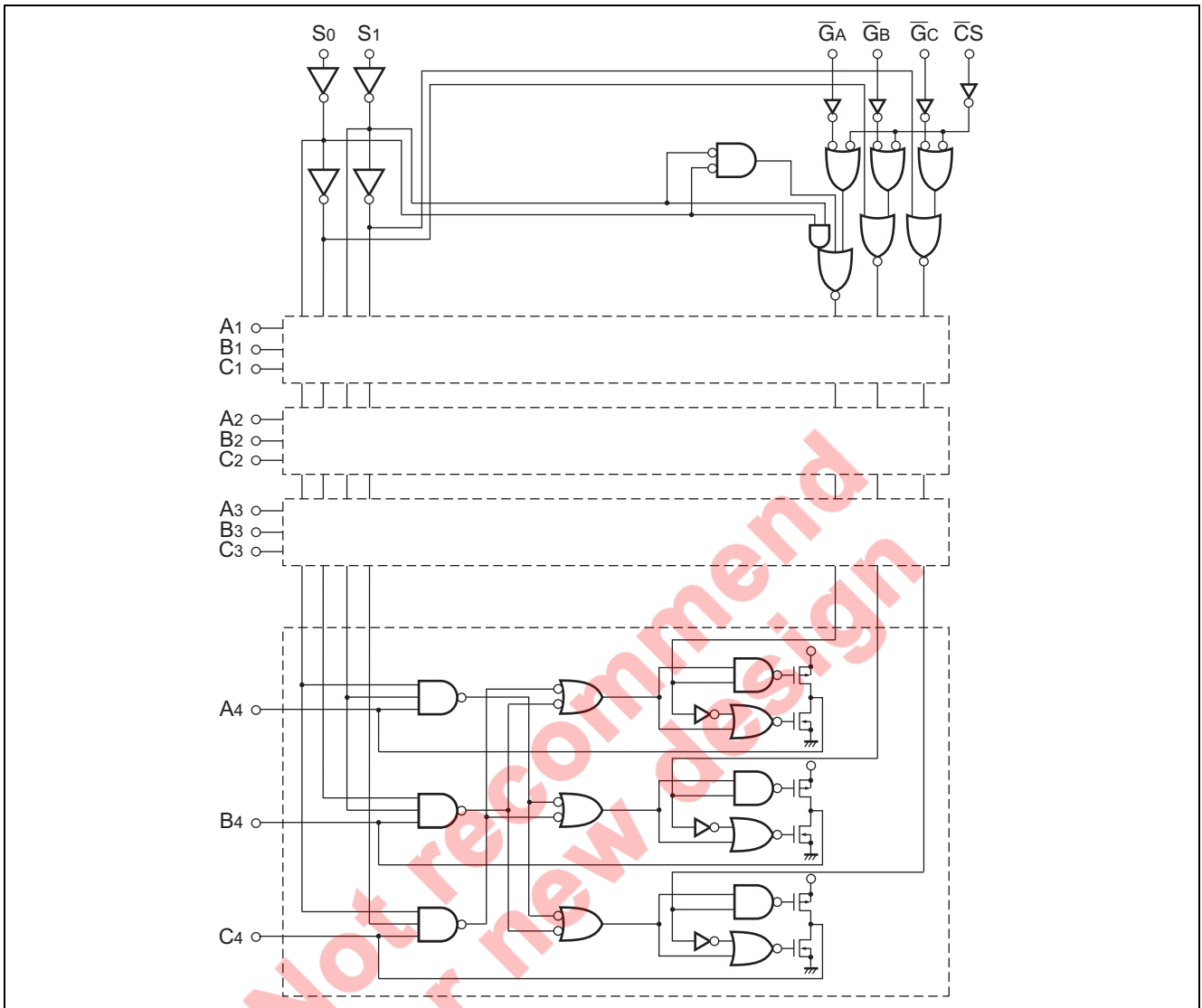
H : high level  
 L : low level  
 X : irrelevant

**Pin Arrangement**

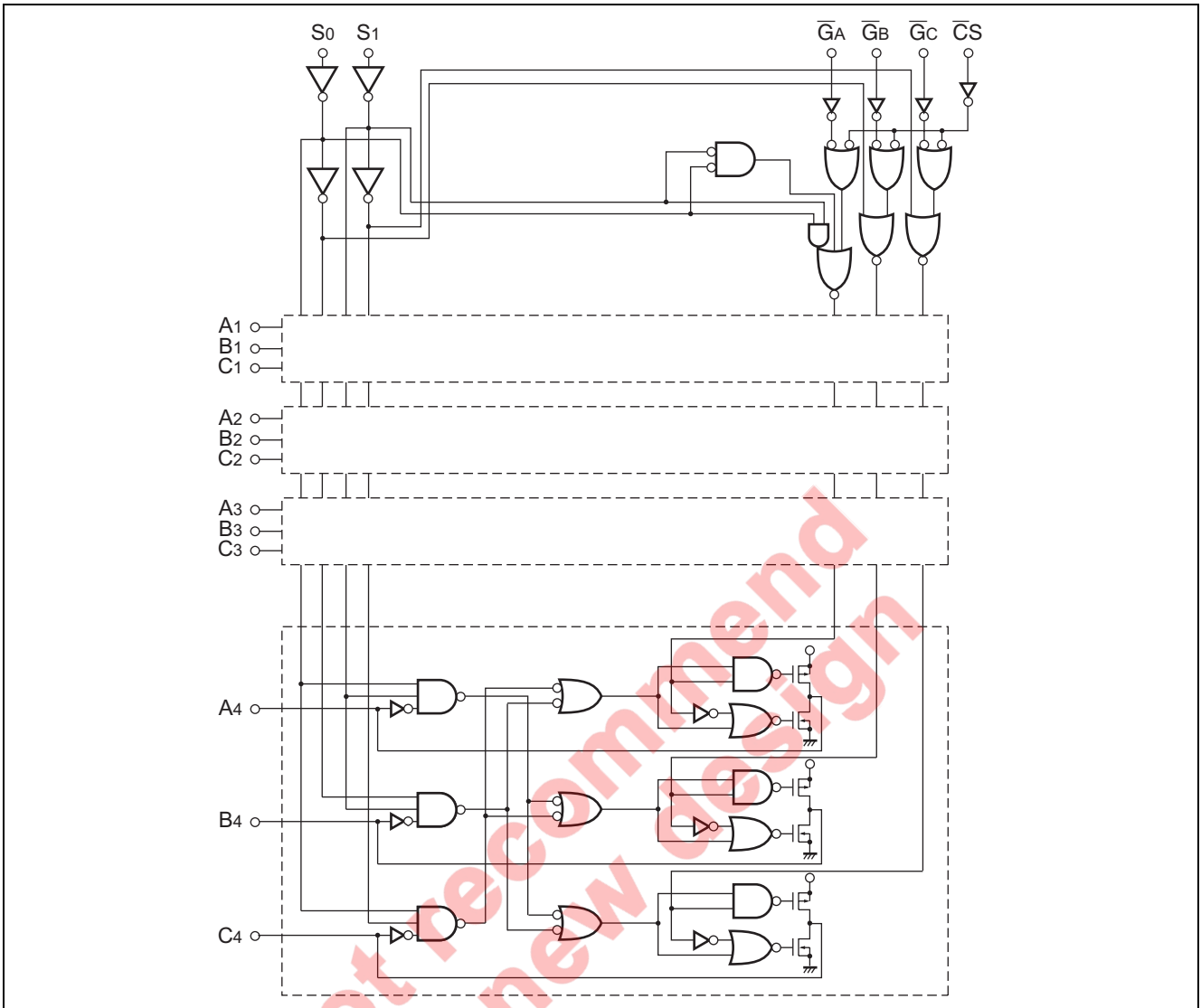


Logic Diagram

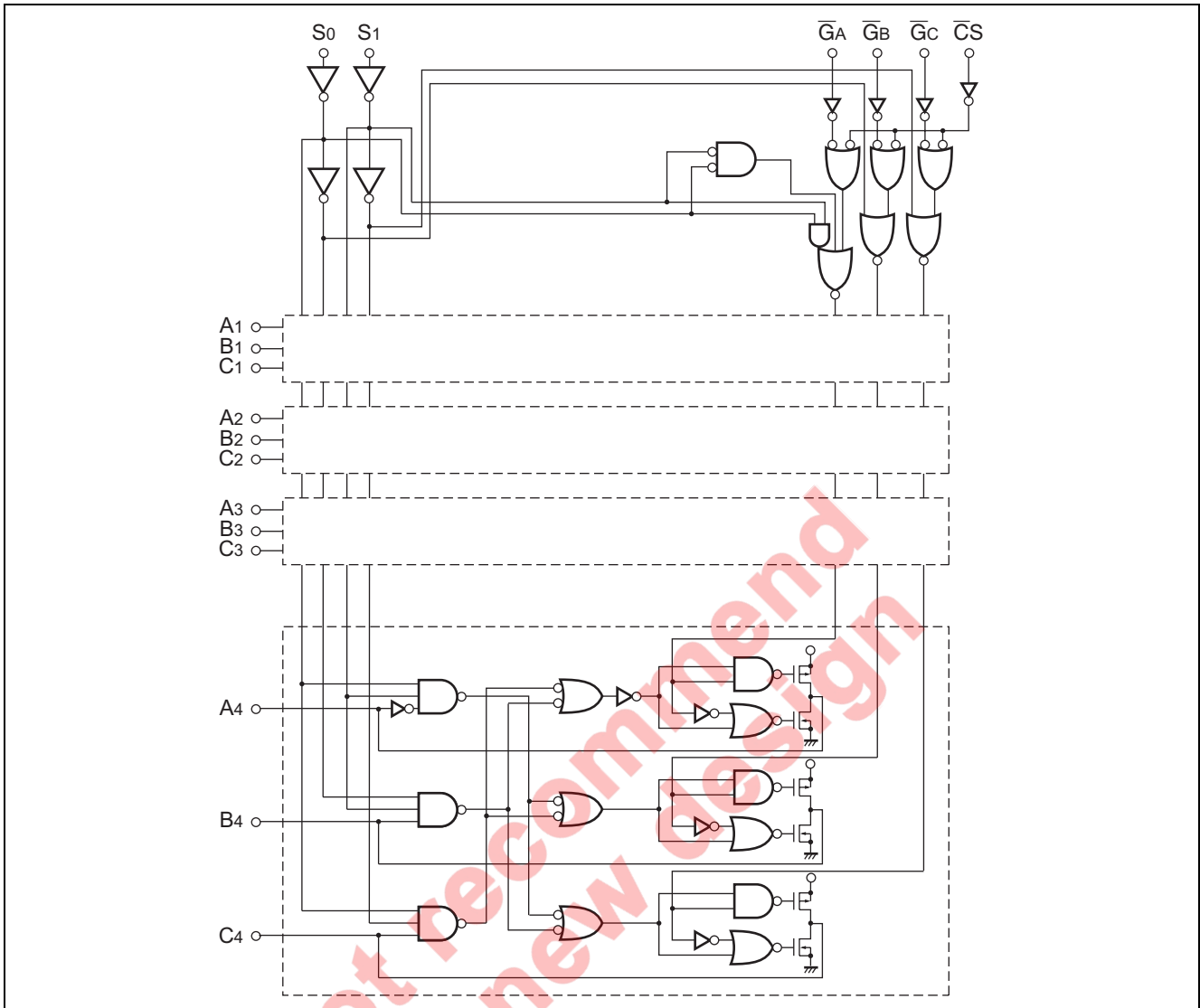
HD74HC442



HD74HC443



HD74HC444



### Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage range	$V_{CC}$	-0.5 to 7.0	V
Input / Output voltage	$V_{IN}, V_{OUT}$	-0.5 to $V_{CC} + 0.5$	V
Input / Output diode current	$I_{IK}, I_{OK}$	$\pm 20$	mA
Output current	$I_O$	$\pm 35$	mA
$V_{CC}$ , GND current	$I_{CC}$ or $I_{GND}$	$\pm 75$	mA
Power dissipation	$P_T$	500	mW
Storage temperature	$T_{stg}$	-65 to +150	°C

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

### Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	$V_{CC}$	2 to 6	V	
Input / Output voltage	$V_{IN}, V_{OUT}$	0 to $V_{CC}$	V	
Operating temperature	$T_a$	-40 to 85	°C	
Input rise / fall time <sup>*1</sup>	$t_r, t_f$	0 to 1000	ns	$V_{CC} = 2.0$ V
		0 to 500		$V_{CC} = 4.5$ V
		0 to 400		$V_{CC} = 6.0$ V

Note: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

### Electrical Characteristics

Item	Symbol	$V_{CC}$ (V)	$T_a = 25^\circ\text{C}$			$T_a = -40$ to $+85^\circ\text{C}$		Unit	Test Conditions	
			Min	Typ	Max	Min	Max			
Input voltage	$V_{IH}$	2.0	1.5	—	—	1.5	—	V		
		4.5	3.15	—	—	3.15	—			
		6.0	4.2	—	—	4.2	—			
	$V_{IL}$	2.0	—	—	0.5	—	0.5	V		
		4.5	—	—	1.35	—	1.35			
		6.0	—	—	1.8	—	1.8			
Output voltage	$V_{OH}$	2.0	1.9	2.0	—	1.9	—	V	$V_{in} = V_{IH}$ or $V_{IL}$	$I_{OH} = -20$ $\mu\text{A}$
		4.5	4.4	4.5	—	4.4	—			$I_{OH} = -6$ mA
		6.0	5.9	6.0	—	5.9	—			$I_{OH} = -7.8$ mA
		4.5	4.18	—	—	4.13	—			
		6.0	5.68	—	—	5.63	—			
	$V_{OL}$	2.0	—	0.0	0.1	—	0.1	V	$V_{in} = V_{IH}$ or $V_{IL}$	$I_{OL} = 20$ $\mu\text{A}$
		4.5	—	0.0	0.1	—	0.1			
		6.0	—	0.0	0.1	—	0.1			
		4.5	—	—	0.26	—	0.33			$I_{OL} = 6$ mA
		6.0	—	—	0.26	—	0.33			$I_{OL} = 7.8$ mA
Off-state output current	$I_{OZ}$	6.0	—	—	$\pm 0.5$	—	$\pm 5.0$	$\mu\text{A}$	$V_{in} = V_{IH}$ or $V_{IL}$ , $V_{out} = V_{CC}$ or GND	
Input current	$I_{in}$	6.0	—	—	$\pm 0.1$	—	$\pm 1.0$	$\mu\text{A}$	$V_{in} = V_{CC}$ or GND	
Quiescent supply current	$I_{CC}$	6.0	—	—	4.0	—	40	$\mu\text{A}$	$V_{in} = V_{CC}$ or GND, $I_{out} = 0$ $\mu\text{A}$	

**Switching Characteristics** ( $C_L = 50 \text{ pF}$ , Input  $t_r = t_f = 6 \text{ ns}$ )

Item	Symbol	$V_{CC} \text{ (V)}$	$T_a = 25^\circ\text{C}$			$T_a = -40 \text{ to } +85^\circ\text{C}$		Unit	Test Conditions
			Min	Typ	Max	Min	Max		
Propagation delay time	$t_{PLH}$	2.0	—	—	200	—	250	ns	
	$t_{PHL}$	4.5	—	—	40	—	50		
		6.0	—	—	34	—	43		
Output enable time	$t_{ZH}$	2.0	—	—	150	—	190	ns	
	$t_{ZL}$	4.5	—	—	30	—	38		
		6.0	—	—	26	—	33		
Output disable time	$t_{HZ}$	2.0	—	—	150	—	190	ns	
	$t_{LZ}$	4.5	—	—	30	—	38		
		6.0	—	—	26	—	33		
Output rise/fall time	$t_{TLH}$	2.0	—	—	60	—	75	ns	
	$t_{THL}$	4.5	—	—	12	—	15		
		6.0	—	—	10	—	13		
Input capacitance	$C_{in}$	—	—	5	10	—	10	pF	

**Package Dimensions**

JEITA Package Code	RENEASAS Code	Previous Code	MASS[Typ.]
P-SOP20-7.5x12.8-1.27	PRSP0020DC-A	FP-20DBV	0.52g

NOTE:  
 1. DIMENSIONS\*\*1 (Nom)\*\*AND\*\*2\*  
 @ DO NOT INCLUDE MOLD FLASH.  
 2. DIMENSION\*\*3\* DOES NOT  
 @ INCLUDE TRIM OFFSET.

Terminal cross section  
( Ni/Pd/Au plating )

Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	—	12.80	13.2
E	—	7.50	—
A <sub>2</sub>	—	—	—
A <sub>1</sub>	0.10	0.20	0.30
A	—	—	2.65
b <sub>p</sub>	0.34	0.40	0.46
b <sub>1</sub>	—	—	—
c	0.20	0.25	0.30
c <sub>1</sub>	—	—	—
θ	0°	—	8°
H <sub>E</sub>	10.00	10.40	10.65
Ⓜ	—	1.27	—
x	—	—	0.12
y	—	—	0.15
Z	—	—	0.935
L	0.40	0.70	1.27
L <sub>1</sub>	—	1.45	—

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